

SPECIFICATION

Device Name : IGBT Module

Type Name : 7MBR35SB120-01

Spec. No. : MS6M 0554

Date : Jun. - 02 - 2000

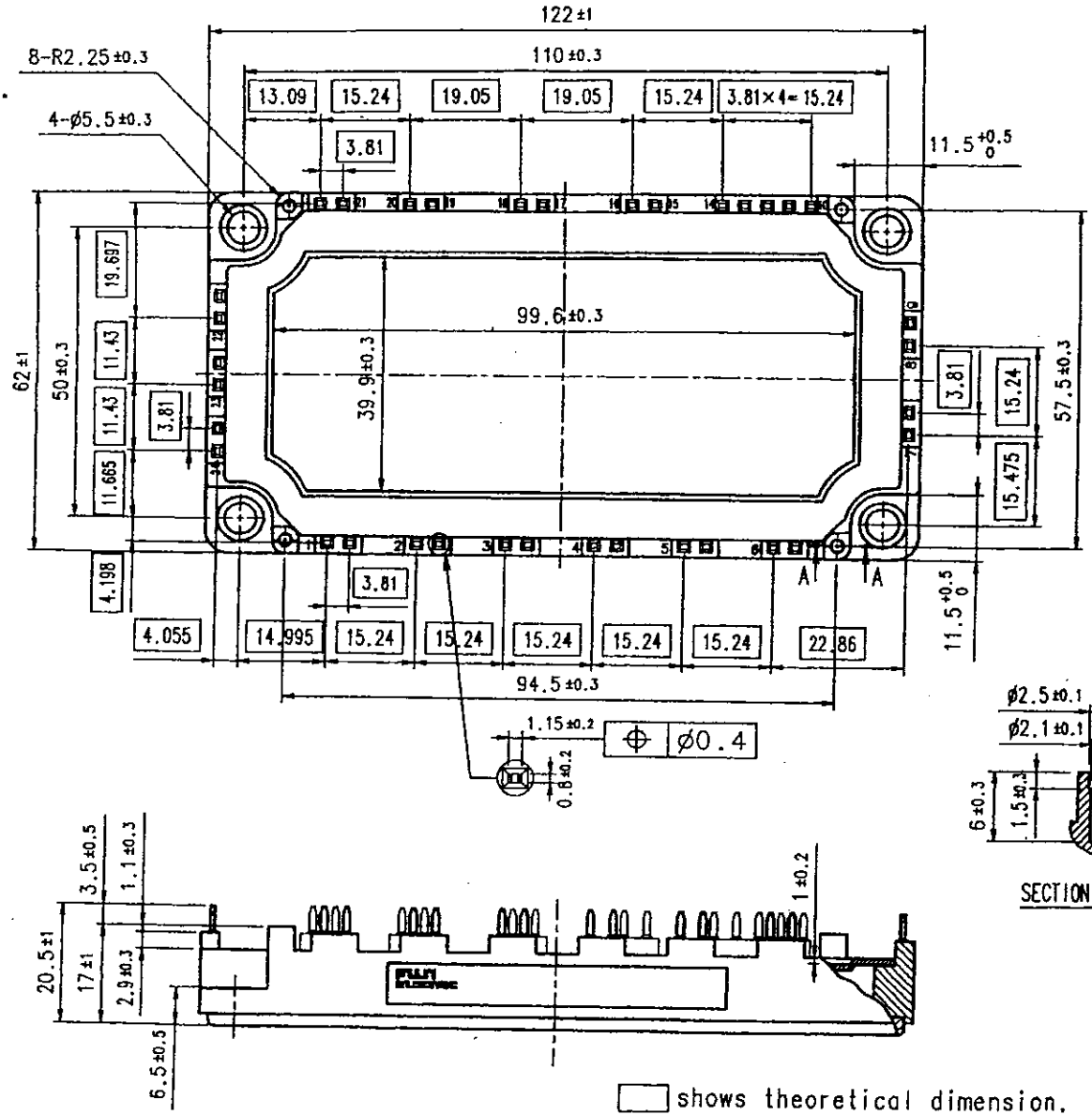
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Matsumoto Factory

	DATE	NAME	APPROVED	Fuji Electric Co., Ltd.		
DRAWN	Jun. - 2 - '00	T. Kobayashi	<i>T. Kobayashi</i>	DWG. NO.	MS6M 0554	1 / 10
CHECKED	June - 2 - 00	S. Matsu				
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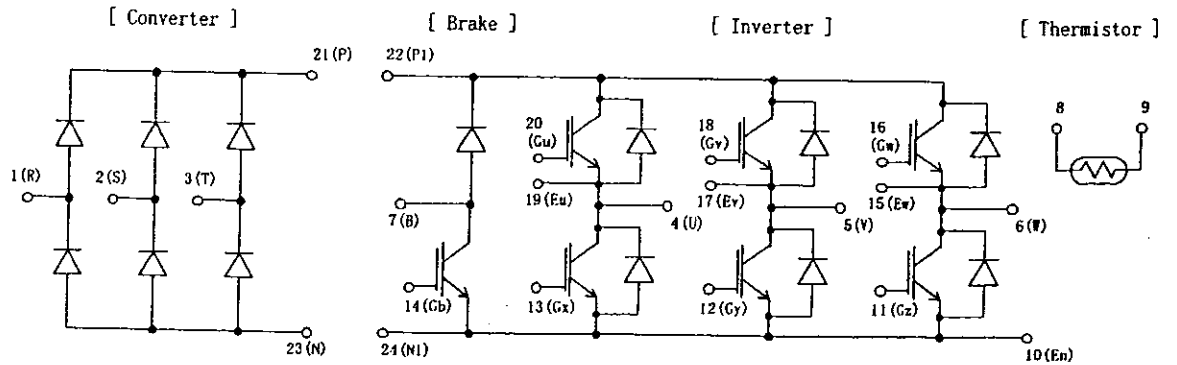
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1. Outline Drawing (Unit : mm)



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2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions	Maximum Ratings	Units	
Inverter	Collector-Emitter voltage	VCES		1200	V	
	Gate-Emitter voltage	VGES		+20	V	
	Collector current	Ic	Continuous	Tc=25C	50	A
				Tc=80C	35	
		Icp	1ms	Tc=25C	100	A
				Tc=80C	70	
	-Ic			35	A	
Collector Power Dissipation	Pc	1 device		240	W	
Brake	Collector-Emitter voltage	VCES		1200	V	
	Gate-Emitter voltage	VGES		+20	V	
	Collector current	Ic	Continuous	Tc=25C	35	A
				Tc=80C	25	
		Icp	1ms	Tc=25C	70	A
				Tc=80C	50	
Collector Power Dissipation	Pc	1 device		180	W	
Repetitive peak reverse Voltage(Diode)	VRRM			1200	V	
Converter	Repetitive peak reverse Voltage	VRRM		1600	V	
	Average Output Current	Io	50Hz/60Hz sine wave	35	A	
	Surge Current (Non-Repetitive)	IFSM	Tj=150C,10ms	360	A	
	I ² t (Non-Repetitive)	I ² t	half sine wave	648	A ² s	
	Junction temperature	Tj		150	C	
Storage temperature	Tstg		-40~ +125	C		
Isolation voltage	between terminal and copper base ^(*)	Viso	AC : 1min.	2500	V	
	between thermistor and others ^(*)			2500	V	
Mounting Screw Torque ^(*)				3.5	Nm	

(*1) All terminals should be connected together when isolation test will be done.

(*2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*3) Recommendable Value : 2.5~3.5 Nm (M5)

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4. Electrical characteristics (at Tj= 25C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units			
			min.	typ.	Max.				
Inverter	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE= 1200 V		1.0	mA			
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE= +20 V		200	nA			
	Gate-Emitter threshold voltage	VGE(th)	VCE = 20 V, Ic = 35 mA		5.5	7.2	8.5	V	
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip			2.1		V	
			Ic = 35 A terminal			2.25	2.7		
	Input capacitance	Cies	VGE = 0 V, VCE= 10 V f = 1 MHz		4200			pF	
	Turn-on time	ton	Vcc= 600 V			0.35	1.2	us	
			Ic = 35 A			0.25	0.6		
			VGE = +15 V			0.1			
	Turn-off time	toff	RG = 33 ohm				0.45	1.0	
					0.08	0.3			
Forward on voltage	VF	IF = 35 A	chip			2.3		V	
			terminal			2.45	3.3		
Reverse recovery time	trr	IF = 35 A				350	ns		
Brake	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE = 1200 V		1.0		mA		
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = +20 V		200		nA		
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip			2.1		V	
			Ic = 25 A terminal			2.25	2.7		
	Turn-on time	ton	Vcc= 600 V			0.35	1.2	us	
			Ic = 25 A			0.25	0.6		
	Turn-off time	toff	VGE = +15 V				0.45	1.0	
RG = 51 ohm					0.08	0.3			
Reverse current	IRRM	VR = 1200 V				1.0	mA		
Converter	VFM	IF = 35 A	chip			1.1		V	
			terminal			1.2	1.5		
Reverse current	IRRM	VR = 1600 V				1.0	mA		
Thermistor	R	T = 25C				5000		ohm	
		T = 100C				465	495	520	
B value	B	T = 25/50C				3305	3375	3450	K

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5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			0.52	C/W
		Inverter FWD			0.90	
		Brake IGBT			0.69	
		Converter Diode			0.75	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

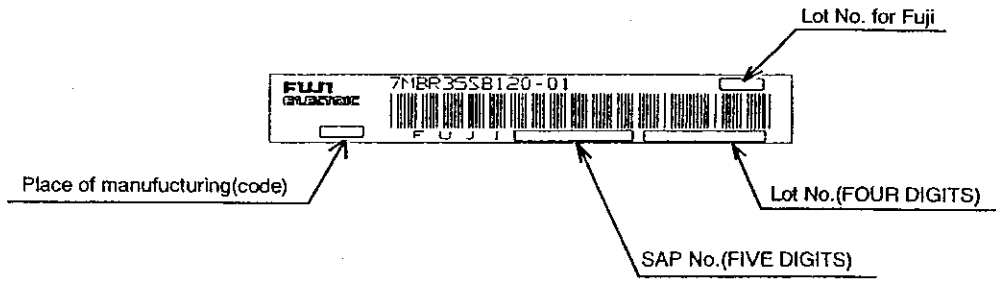
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6. Indication on module



7. Applicable category

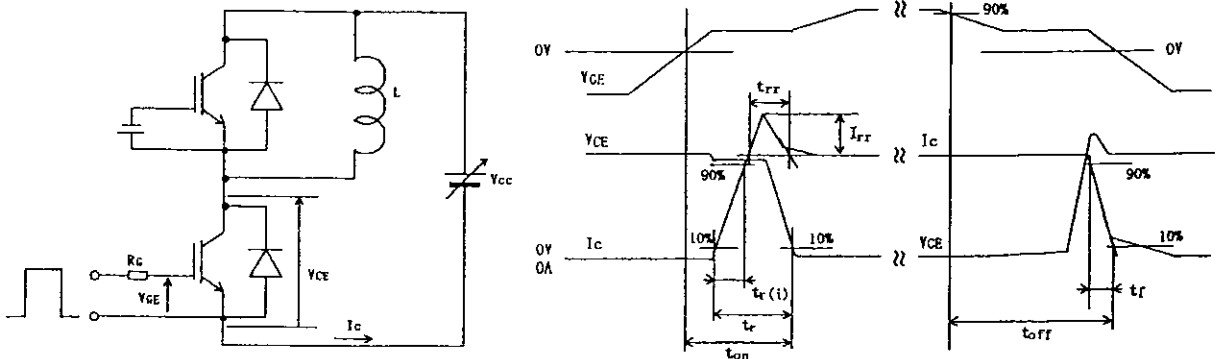
This specification is applied to Power Integrated Module named 7MBR35SB120-01 .

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

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9. Definitions of switching time



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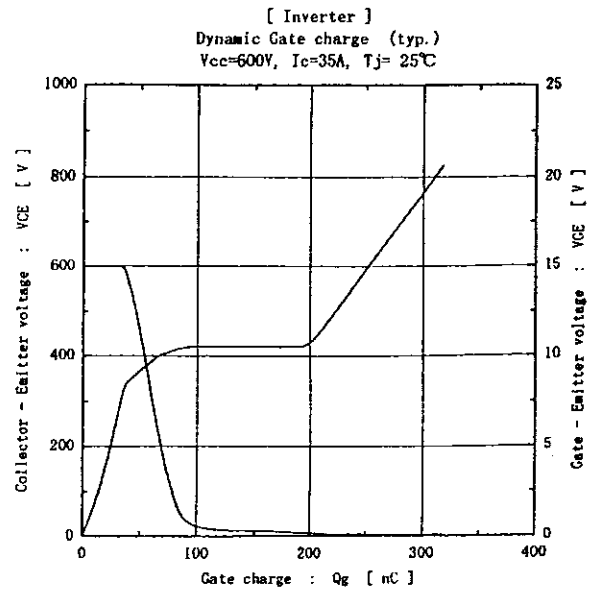
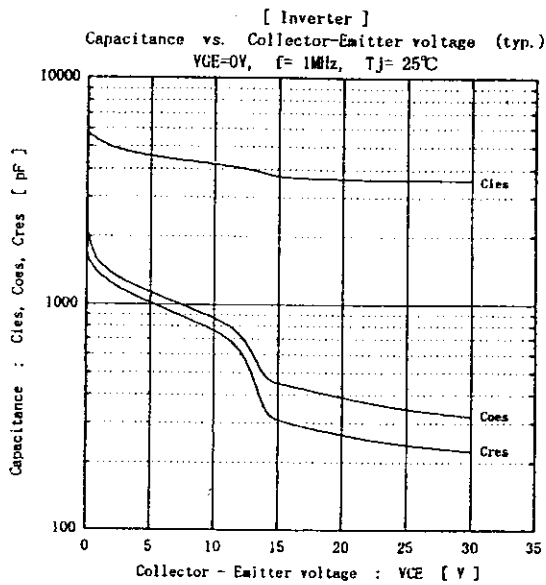
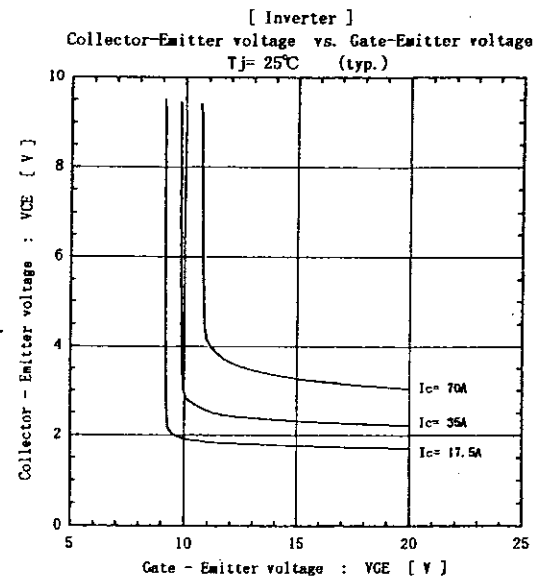
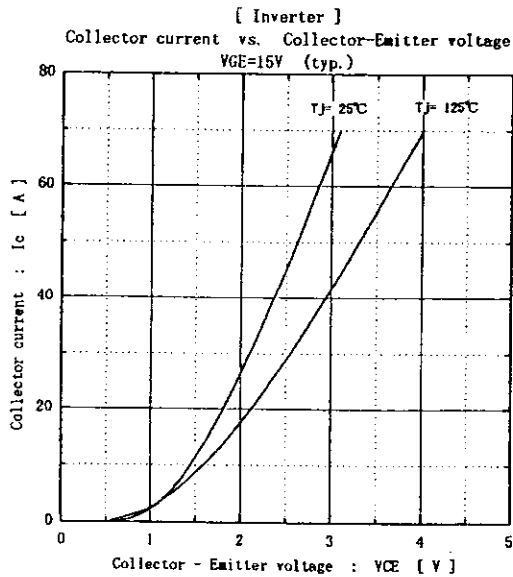
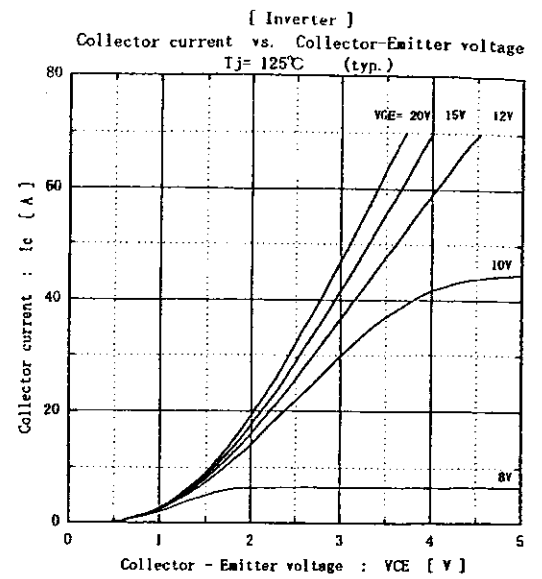
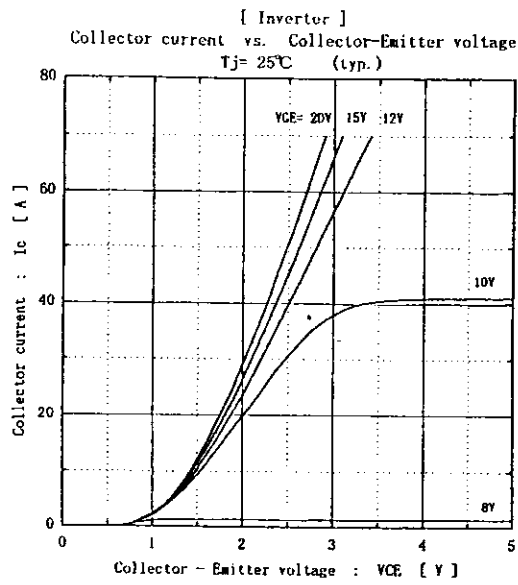
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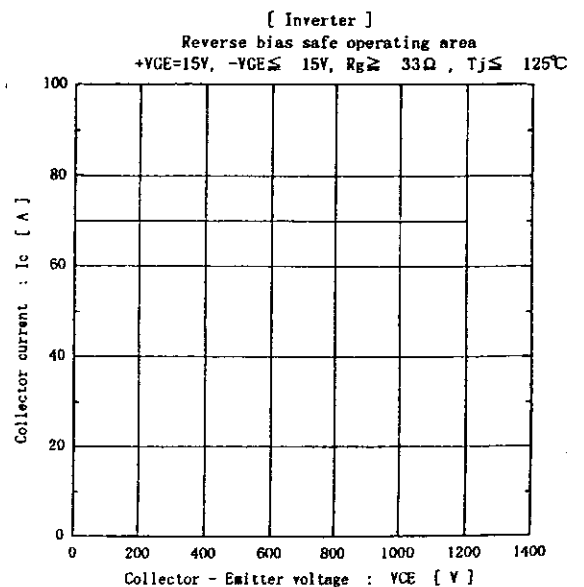
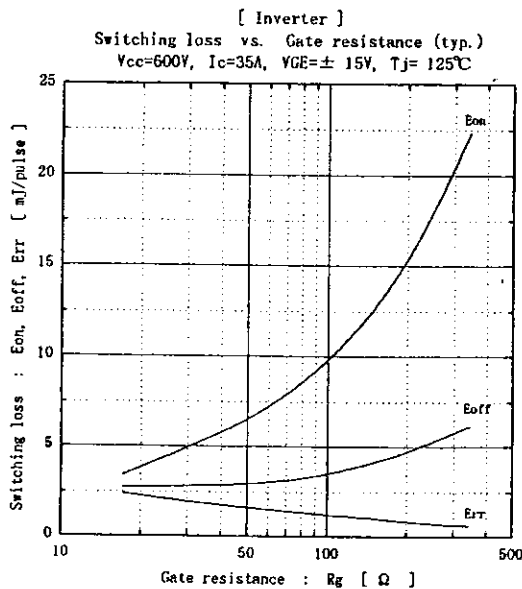
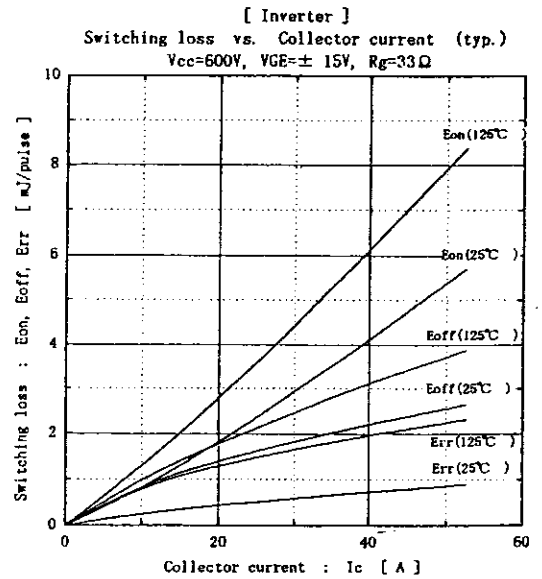
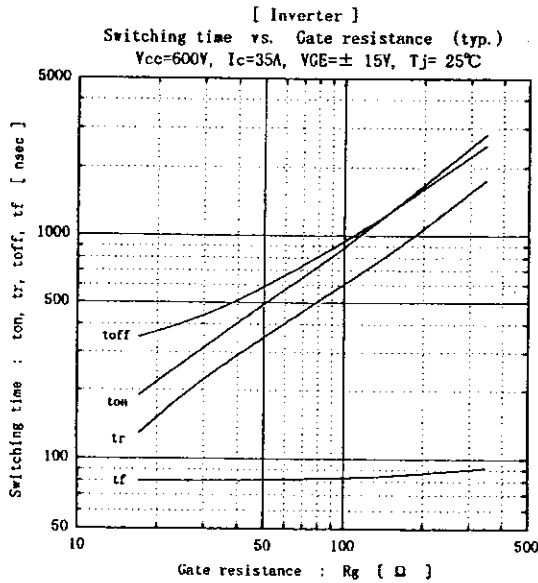
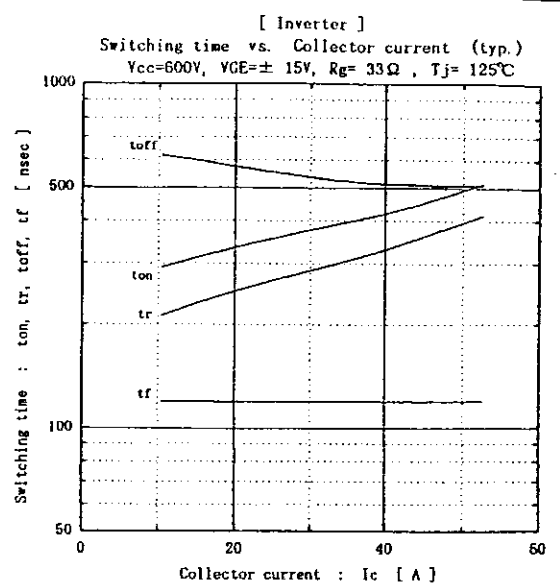
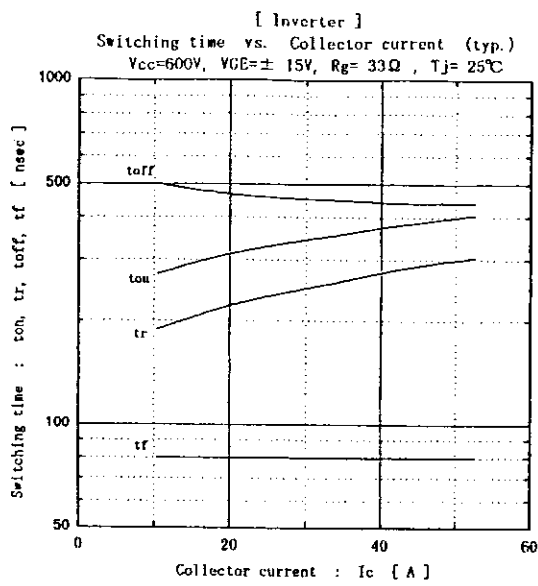
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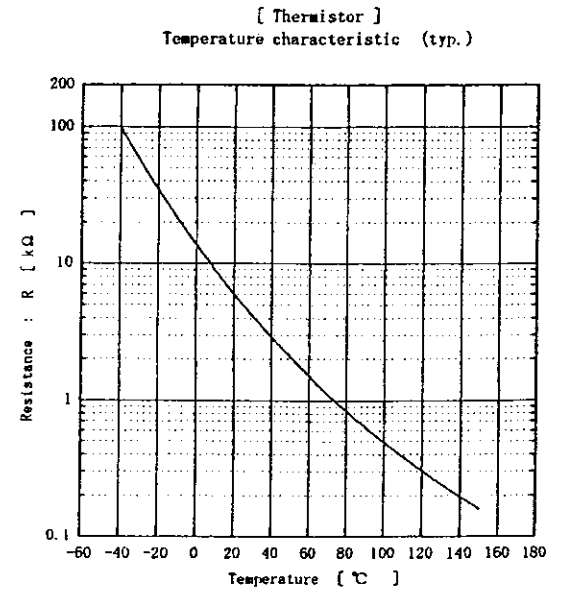
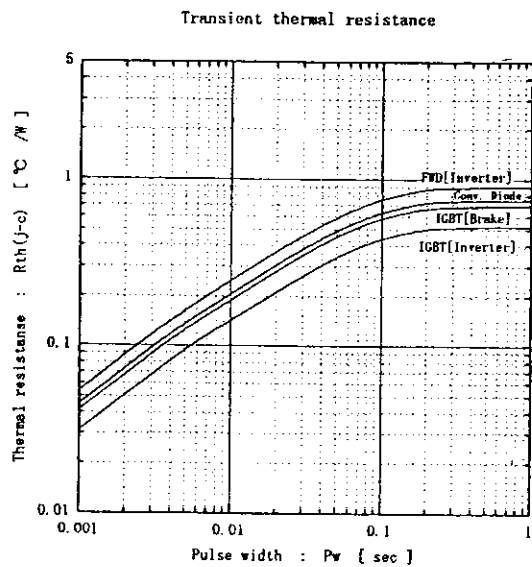
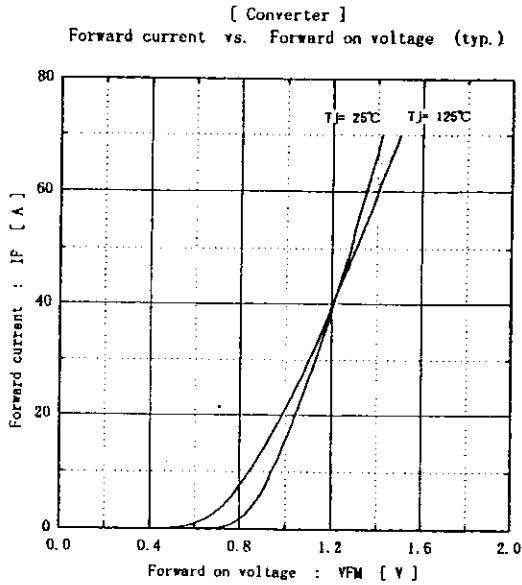
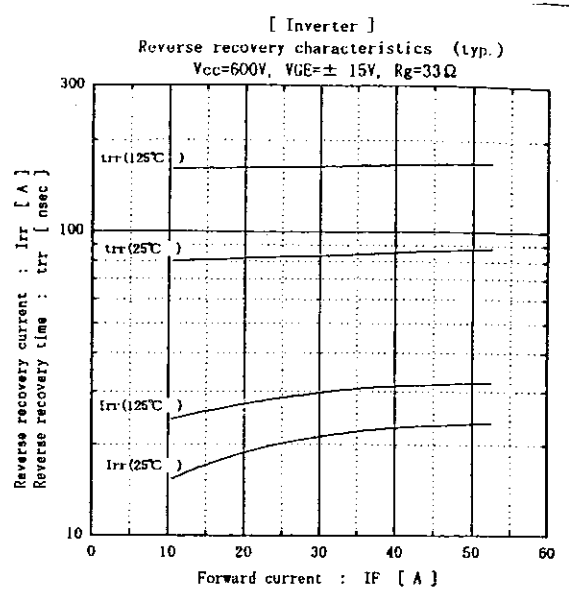
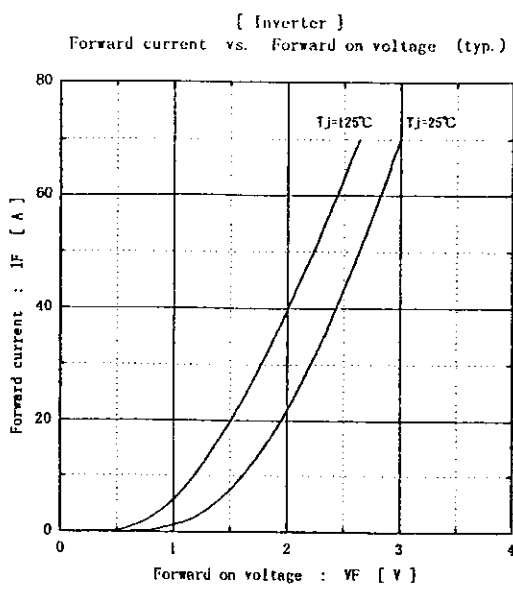
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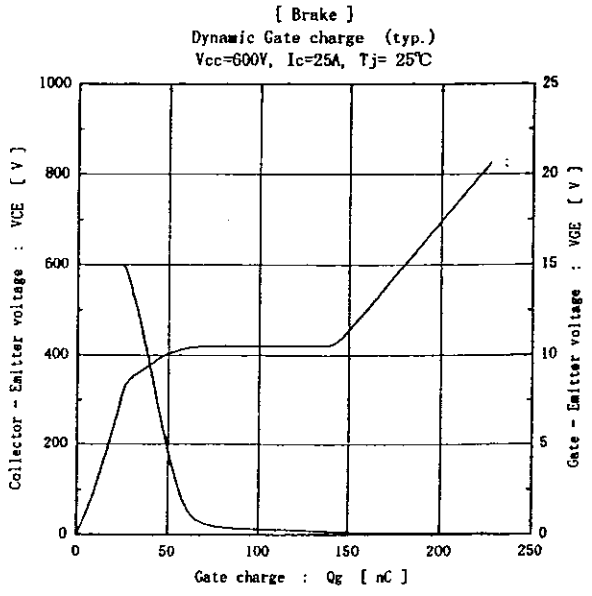
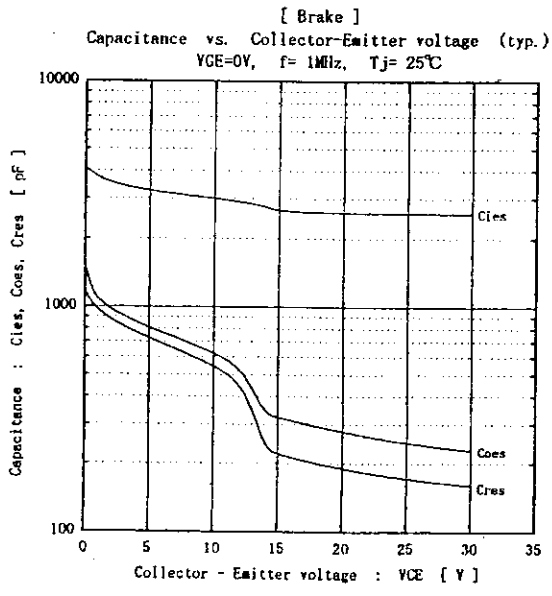
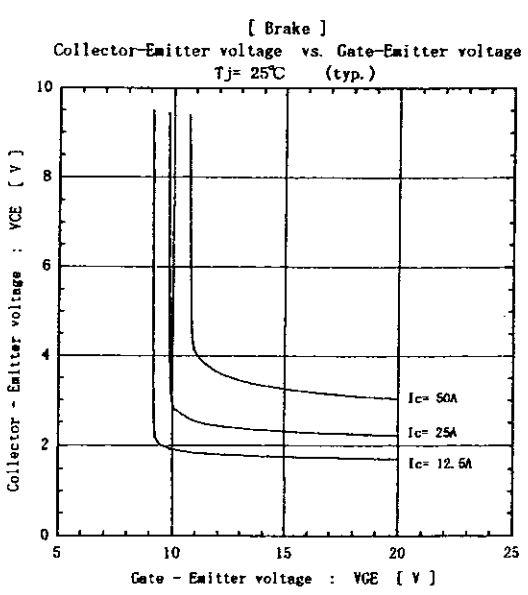
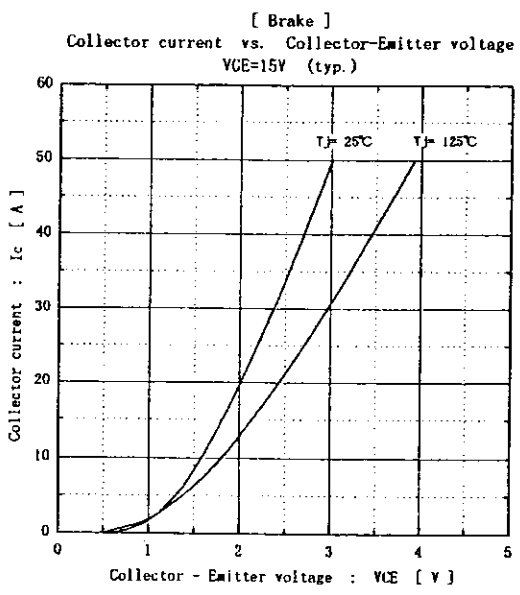
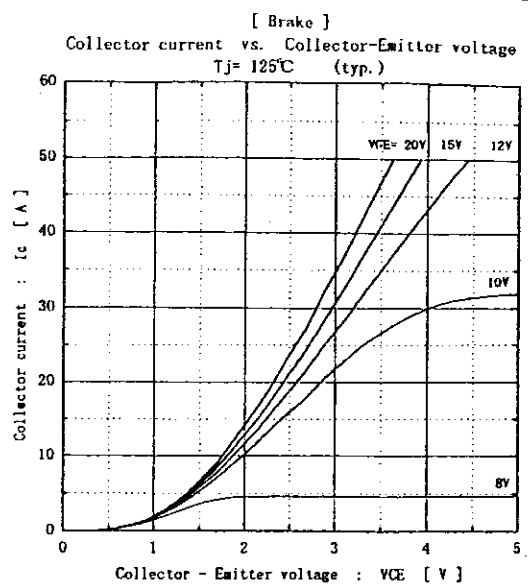
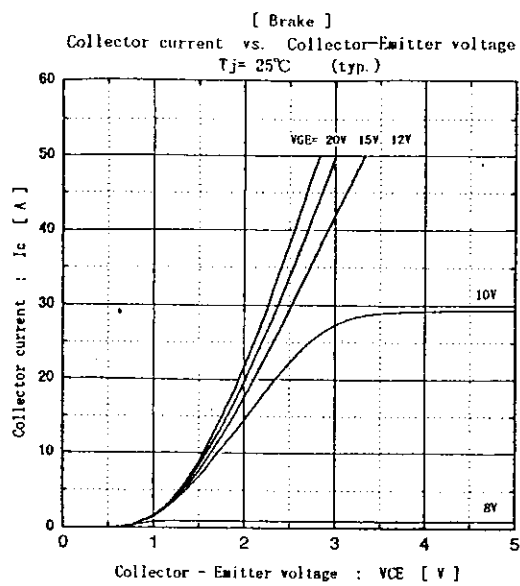
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